### SUBMINIATURE SOLID STATE LAMP

PRELIMINARY SPEC

Part Number: KM2520SYC09

Super Bright Yellow

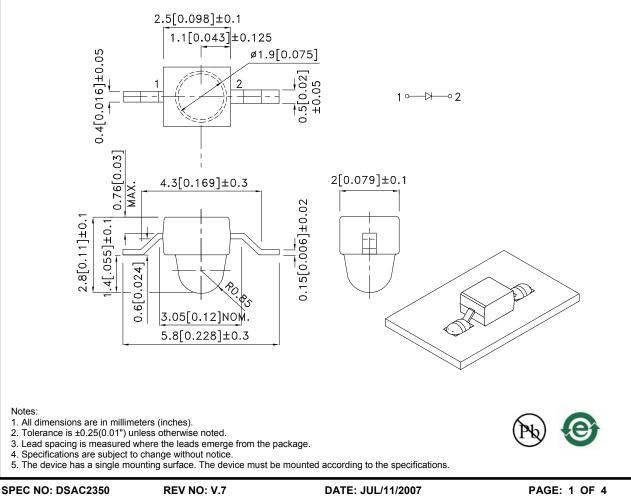
#### **Features**

- SUBMINIA TURE PACKAGE.
- WIDE VIEWING ANGLE.
- Z-BEND LEAD.
- LONG LIFE SOLID STATE RELIABILITY.
- LOW PACKAGE PROFILE.
- MOISTURE SENSITIVITY LEVEL : LEVEL 3.
- PACKAGE : 1000PCS / REEL.
- RoHS COMPLIANT.

#### Description

The Super Bright Yellow device is made with InGaAIP (on GaAs substrate) light emitting diode chip.

#### **Package Dimensions**



**APPROVED: WYNEC** 

Notes:

**CHECKED: Allen Liu** 

DRAWN: Y.L.LI

ERP: 1202000716

### Selection Guide

Part No.	Dice	Lens Type	lv (mcd) [2] @ 20mA		Viewing Angle [1]
			Min.	Тур.	201/2
KM2520SYC09	Super Bright Yellow (InGaAIP)	WATER CLEAR	900	1500	20°

Notes:

θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.
Luminous intensity/ luminous Flux: +/-15%.

### Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Super Bright Yellow	590		nm	IF=20mA
λD [1]	Dominant Wavelength	Super Bright Yellow	588		nm	I⊧=20mA
Δλ1/2	Spectral Line Half-width	Super Bright Yellow	28		nm	I⊧=20mA
С	Capacitance	Super Bright Yellow	25		pF	VF=0V;f=1MHz
VF [2]	Forward Voltage	Super Bright Yellow	2	2.5	V	I⊧=20mA
lr	Reverse Current	Super Bright Yellow		10	uA	Vr=5V

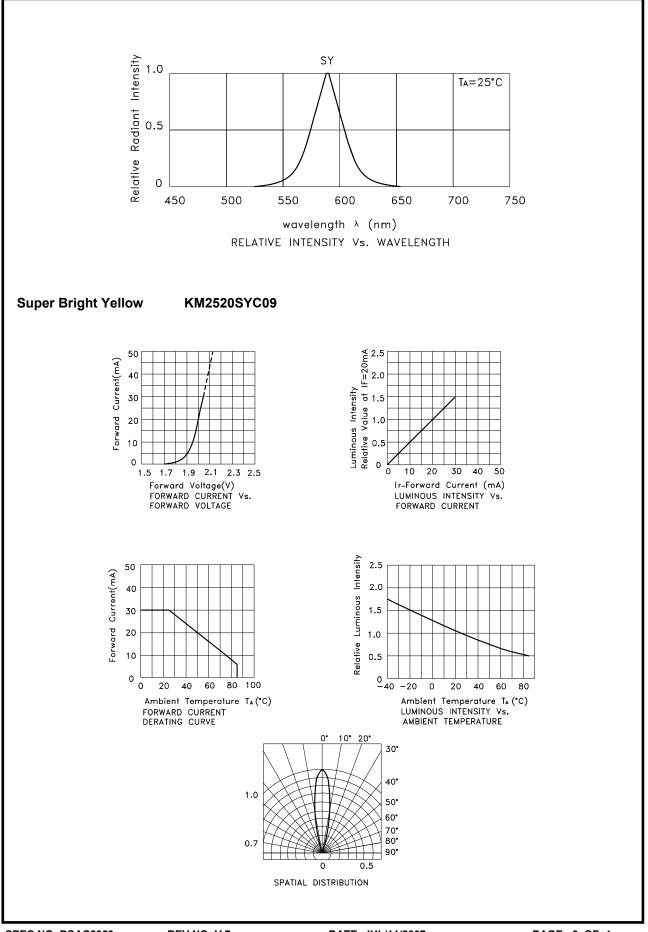
Notes:

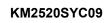
1.Wavelength: +/-1nm. 2. Forward Voltage: +/-0.1V.

### Absolute Maximum Ratings at TA=25°C

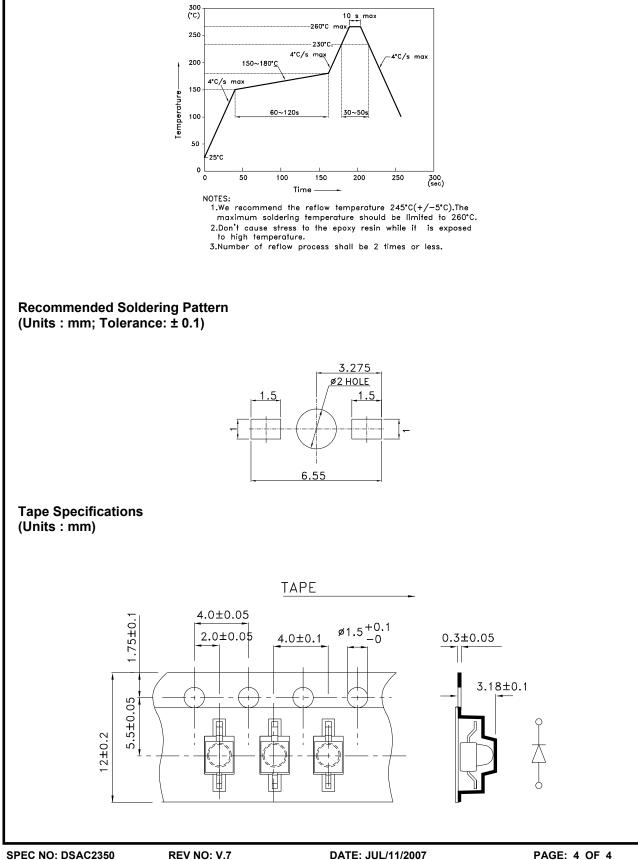
Parameter	Super Bright Yellow	Units		
Power dissipation	75	mW		
DC Forward Current	30	mA		
Peak Forward Current [1]	150	mA		
Reverse Voltage	5	V		
Operating Temperature	-40°C To +85°C			
Storage Temperature	-40°C To +85°C			

Note: 1. 1/10 Duty Cycle, 0.1ms Pulse Width.





Reflow Soldering Profile For Lead-free SMT Process.



REV NO: V.7 CHECKED: Allen Liu DATE: JUL/11/2007 DRAWN: Y.L.LI PAGE: 4 OF 4 ERP: 1202000716